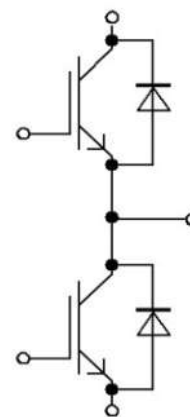


C2 series package: 1200V 300A IGBT module

[Datasheet](#)



Equivalent
Circuit Schematic

Features:

- Trenchgate Gen.7 IGBT technology
- $V_{CE(sat)}$ with positive temperature coefficient
- High RBSOA capability
- Low static losses: $V_{CE(sat)} = 1,5V@25^{\circ}C$
- Low dynamic losses

Options:

- Pre-applied TIM (option +M01)
- Adoption for parallel connection (Vf selection)

Typical Applications:

- High Power Converters
- Motor Drives
- Uninterrupted Power Supply
- Photovoltaic

IGBT, Inverter / IGBT

Maximum Rated Values

Collector-emitter Voltage	$T_{vj} = 25^{\circ}\text{C}$	V_{CES}	1200	V
Continuous DC Collector Current		I_{Cnom}	300	A
	$T_C = 80^{\circ}\text{C}, T_{vj\ max} = 175^{\circ}\text{C}$	I_C	390	A
Repetitive Peak Collector Current	$I_{CRM} = 2 \times I_{Cnom}$	I_{CRM}	600	A
Total Power Dissipation	$T_C = 25^{\circ}\text{C}, T_{vj\ max} = 175^{\circ}\text{C}$	P_{tot}	1440	W
Gate-emitter Peak Voltage		V_{GES}	± 20	V

Characteristic Values

		min. typ. max.				
Collector-emitter Saturation Voltage ¹⁾	$I_C = 300\text{A}, V_{GE} = 15\text{V}$ $T_{vj} = 25^{\circ}\text{C}$ $T_{vj} = 125^{\circ}\text{C}$ $T_{vj} = 150^{\circ}\text{C}$ $T_{vj} = 175^{\circ}\text{C}$	V_{CEsat}		1.50 1.71 1.87 1.93	1.70	V
Gate Threshold Voltage	$V_{CE} = V_{GE}, I_C = 12\text{mA}, T_{vj} = 25^{\circ}\text{C}$	V_{GEth}	5.0	6.0	7.0	V
Gate Charge	$V_{GE} = -15\text{V} \dots +15\text{V}$	Q_G	—	tbd	—	μC
Internal Gate Resistor	$T_{vj} = 25^{\circ}\text{C}$	R_{Gint}	—	0.9	—	Ω
Input Capacitance	$V_{CE} = 25\text{V}, V_{GE} = 0\text{V}$ $f = 1\text{MHz}$	C_{ies}	—	tbd	—	nF
Reverse Transfer Capacitance		C_{res}	—	tbd	—	nF
Collector-emitter Cutoff Current	$V_{CE} = 1200\text{V}, V_{GE} = 0\text{V}, T_{vj} = 25^{\circ}\text{C}$	I_{CES}	—	—	100	μA
Gate-emitter Leakage Current	$V_{CE} = 0\text{V}, V_{GE} = \pm 20\text{V}, T_{vj} = 25^{\circ}\text{C}$	I_{GES}	—	—	± 100	nA
Turn-on Delay Time, Inductive Load	$I_C = 300\text{A}, V_{CE} = 600\text{V}$ $V_{GE} = 15\text{V}/-8\text{V}$ $R_{GON} = 1.5\Omega$ $T_{vj} = 25^{\circ}\text{C}$ $T_{vj} = 125^{\circ}\text{C}$ $T_{vj} = 150^{\circ}\text{C}$ $T_{vj} = 175^{\circ}\text{C}$	t_{don}	—	265 270 273 275	—	ns
Rise Time, Inductive Load	$I_C = 300\text{A}, V_{CE} = 600\text{V}$ $V_{GE} = 15\text{V}/-8\text{V}$ $R_{gon} = 1.5\Omega$ $T_{vj} = 25^{\circ}\text{C}$ $T_{vj} = 125^{\circ}\text{C}$ $T_{vj} = 150^{\circ}\text{C}$ $T_{vj} = 175^{\circ}\text{C}$	t_r	—	62 72 77 82	—	ns
Turn-off Delay Time, Inductive Load	$I_C = 300\text{A}, V_{CE} = 600\text{V}$ $V_{GE} = 15\text{V}/-8\text{V}$ $R_{goff} = 1.5\Omega$ $T_{vj} = 25^{\circ}\text{C}$ $T_{vj} = 125^{\circ}\text{C}$ $T_{vj} = 150^{\circ}\text{C}$ $T_{vj} = 175^{\circ}\text{C}$	t_{doff}	—	441 490 490 500	—	ns
Fall Time, Inductive Load	$I_C = 300\text{A}, V_{CE} = 600\text{V}$ $V_{GE} = 15\text{V}/-8\text{V}$ $R_{Goff} = 1.5\Omega$ $T_{vj} = 25^{\circ}\text{C}$ $T_{vj} = 125^{\circ}\text{C}$ $T_{vj} = 150^{\circ}\text{C}$ $T_{vj} = 175^{\circ}\text{C}$	t_f	—	128 204 225 245	—	ns
Turn-on Energy Loss per Pulse	$I_C = 300\text{A}, V_{CE} = 600\text{V},$ $L_{\sigma} = 45\text{nH}, V_{GE} = 15\text{V}/-8\text{V},$ $R_{Gon} = 1.5\Omega, di/dt =$ $3000\text{A}/\mu\text{s} (T_{vj} = 175^{\circ}\text{C})$ $T_{vj} = 25^{\circ}\text{C}$ $T_{vj} = 125^{\circ}\text{C}$ $T_{vj} = 150^{\circ}\text{C}$ $T_{vj} = 175^{\circ}\text{C}$	E_{on}	—	20.3 30.4 34.5 37.0	—	mJ
Turn-off energy Loss per Pulse	$I_C = 300\text{A}, V_{CE} = 600\text{V},$ $L_{\sigma} = 45\text{nH}, R_{Goff} = 1.5\Omega$ $V_{GE} = 15\text{V}/-8\text{V}, dv/dt =$ $7000\text{V}/\mu\text{s} (T_{vj} = 175^{\circ}\text{C})$ $T_{vj} = 25^{\circ}\text{C}$ $T_{vj} = 125^{\circ}\text{C}$ $T_{vj} = 150^{\circ}\text{C}$ $T_{vj} = 175^{\circ}\text{C}$	E_{off}	—	25.6 34.2 35.7 38.2	—	mJ

SC Data	VCE = 600V, VGE = 15V/-8V, T _{vj} = 150°C	t _{psc}	8	—	—	μs
Thermal Resistance, Junction to Case	Per IGBT / IGBT	R _{thJC}	—	0.104	—	K/W
Temperature under Switching Conditions		T _{vj op}	-40	—	150	°C

Diode, Inverter Maximum Rated Values

Repetitive Peak Reverse Voltage	T _{vj} = 25°C	V _{RRM}	1200	V
Continuous DC Forward Current		I _F	300	A
Repetitive Peak Forward Current	I _{CRM} = 2 x I _{fnom}	I _{FRM}	600	A

Characteristic Values

		min. typ. max.				
Forward Voltage ¹⁾	I _F = 300A, V _{GE} = 0V T _{vj} = 25°C T _{vj} = 125°C T _{vj} = 150°C T _{vj} = 175°C	V _F		1.92 1.90 1.84 1.78	2.40	V
Peak Reverse Recovery Current	I _F = 300A, V _R = 600V -di _F /dt = 2800A/μs (T _{vj} = 175°C) V _{GE} = -8V T _{vj} = 25°C T _{vj} = 125°C T _{vj} = 150°C T _{vj} = 175°C	I _{RM}	—	170 195 205 210	—	A
Recovery Charge	I _F = 300A, V _R = 600V -di _F /dt = 2800A/μs (T _{vj} = 175°C) V _{GE} = -8V T _{vj} = 25°C T _{vj} = 125°C T _{vj} = 150°C T _{vj} = 175°C	Q _R	—	11.0 28.5 34.5 40.0	—	μC
Reverse Recovery Energy	I _F = 300A, V _R = 600V -di _F /dt = 2800A/μs (T _{vj} = 175°C) V _{GE} = -8V T _{vj} = 25°C T _{vj} = 125°C T _{vj} = 150°C T _{vj} = 175°C	E _{rec}	—	5.8 12.5 15.0 18.0	—	mJ
Thermal Resistance, Junction to Case	Per Doide / Diode	R _{thJC}	—	0.172	—	K/W
Temperature under Switching Conditions		T _{vj op}	-40	—	150	°C

Module

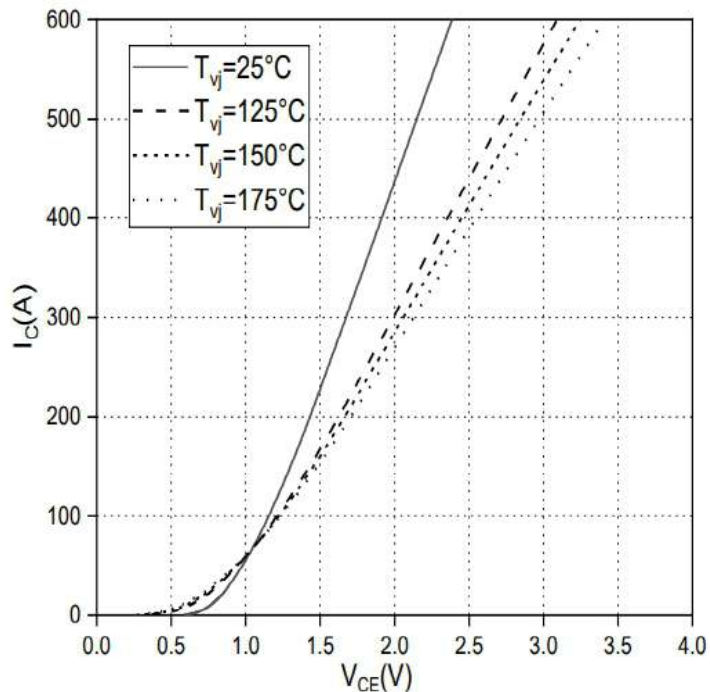
Isolation Test Voltage	RMS, f = 50Hz, t = 1min	V _{ISOL}	3.0	kV
Material of Module Baseplate			Cu	
Internal Isolation	(class 1, IEC 61140) Basic insulation (class 1, IEC 61140)		Al ₂ O ₃	
Creepage Distance	Terminal to heatsink Terminal to terminal		29.0 23.0	mm
Clearance	Terminal to heatsink Terminal to terminal		23.0 11.0	mm
Comparative Tracking Index		CTI	>400	

			min.	typ.	max.	
Stray Inductance Module		L _{sCE}	—	20	—	nH
Module Lead Resistance, Terminals-Chip	T _C = 25°C, Per Switch	R _{CC'+EE'}	—	0.70	—	mΩ
Storage Temperature		T _{stg}	-40	—	125	°C
Modul MountingTorque	M6	M	4.0	—	6.0	Nm
Terminal MountingTorque	M6	M	4.0	—	6.0	Nm
Weight		G	—	320	—	g

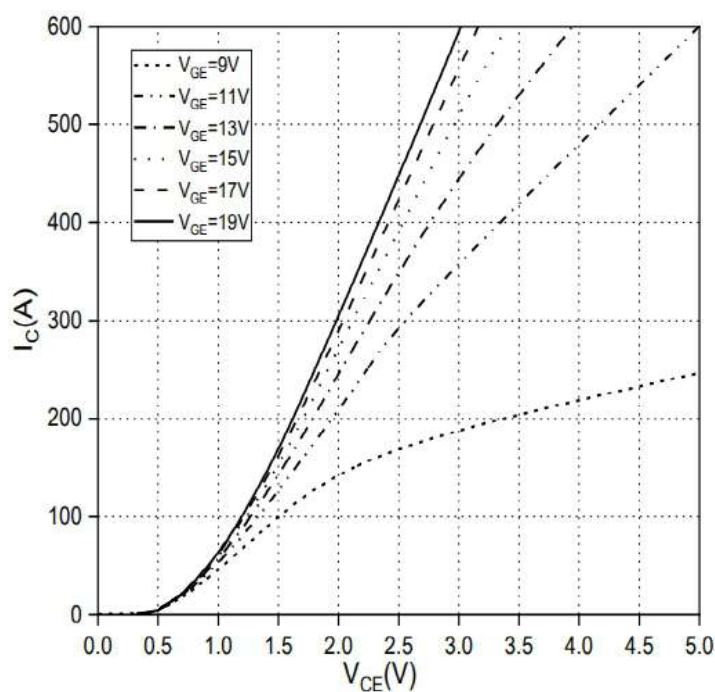
1) Terminal impedance is not included.

Circuit Diagram

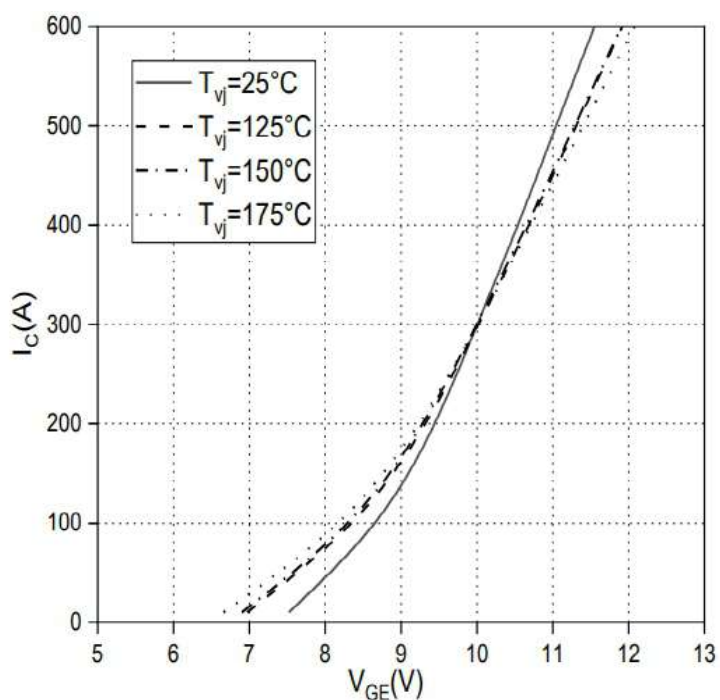
Output characteristic IGBT, Inverter (typical), IGBT
 $I_c = f(V_{CE})$, $V_{GE} = 15V$



Output characteristic IGBT, Inverter (typical), IGBT
 $I_c = f(V_{CE})$, $T_{vj} = 175^\circ C$



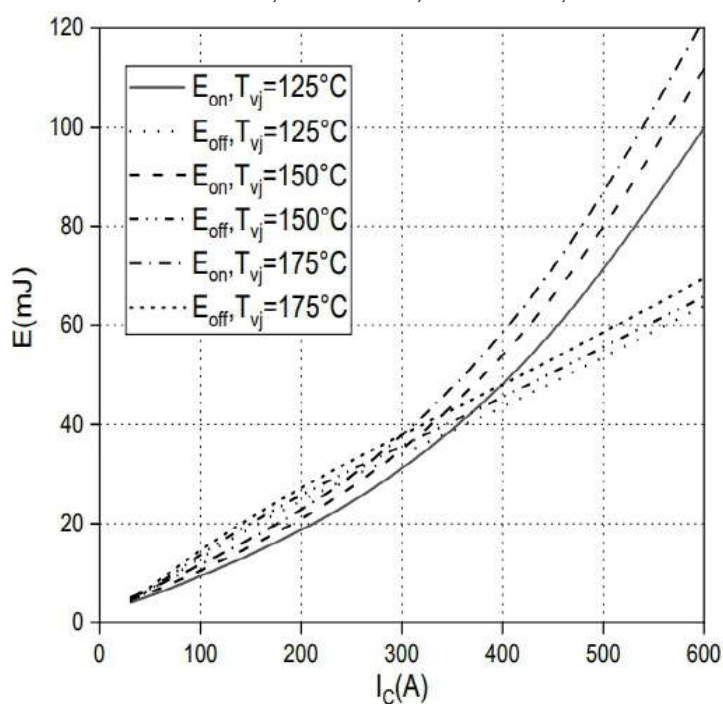
Transfer characteristic IGBT, Inverter (typical), IGBT
 $I_c = f(V_{GE})$, $V_{CE} = 20V$



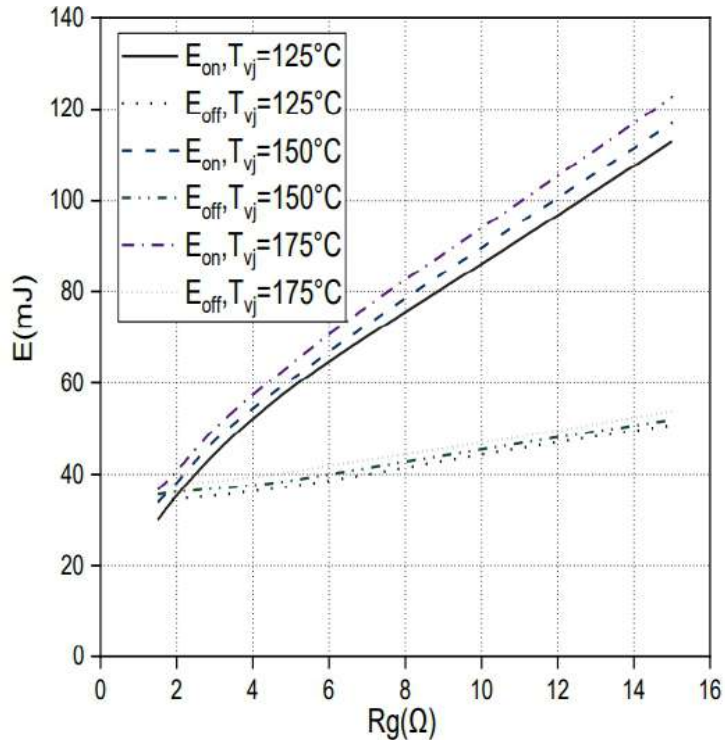
Switching losses IGBT, Inverter (Typical), IGBT

$E_{on} = f(I_c)$, $E_{off} = f(I_c)$

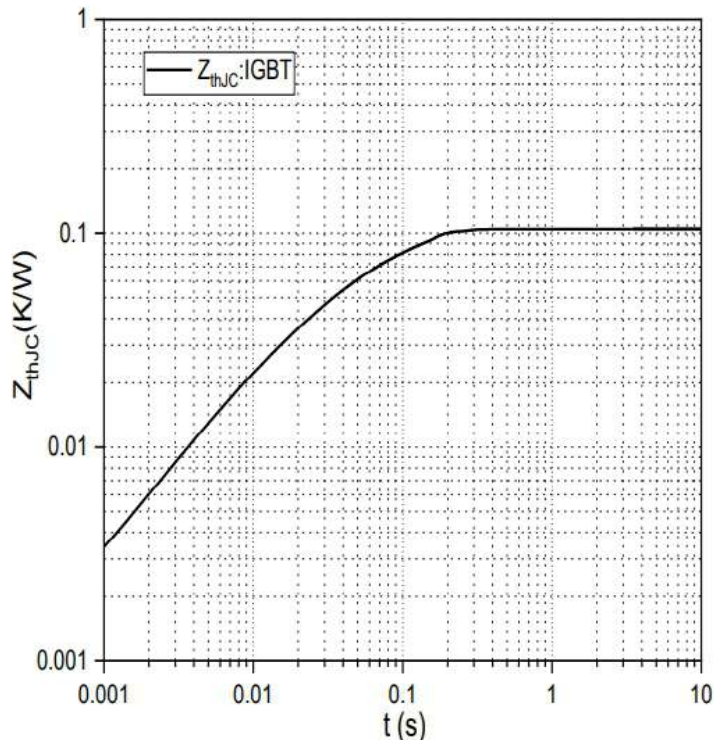
$V_{GE} = +15V/-8V$, $R_{Gon} = 1.5\Omega$, $R_{Goff} = 1.5\Omega$, $V_{CE} = 600V$

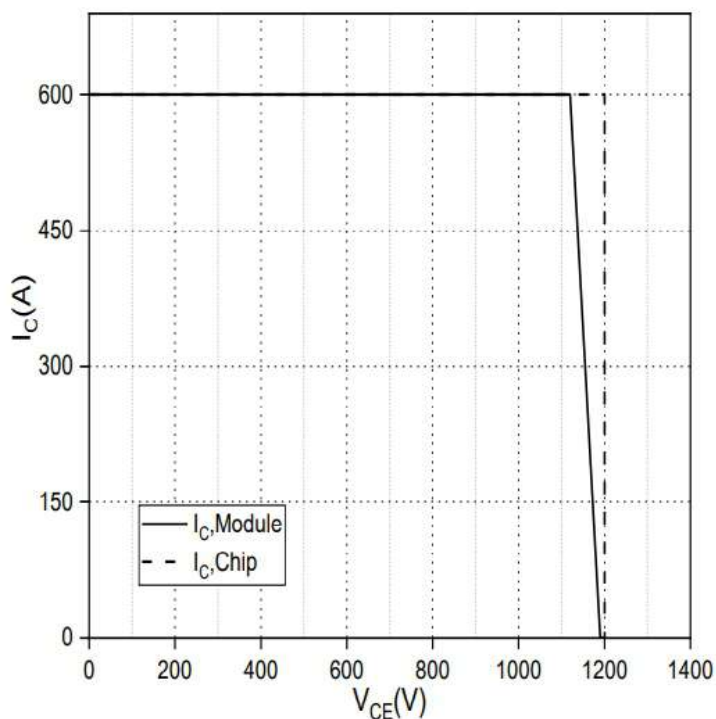


Switching losses IGBT, Inverter (typical), IGBT

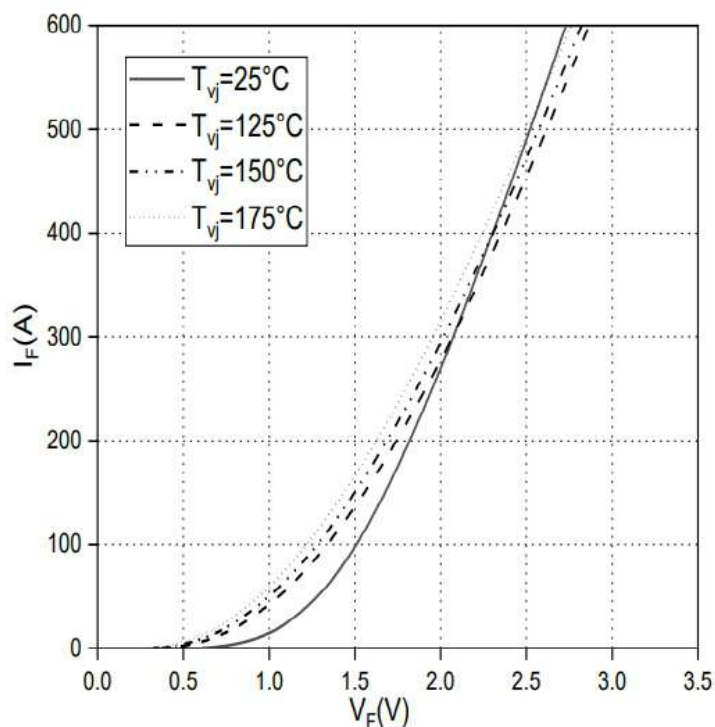
 $V_{GE} = +15V/-8V$, $I_C = 300A$, $V_{CE} = 600V$


Transient thermal impedance IGBT, Inverter

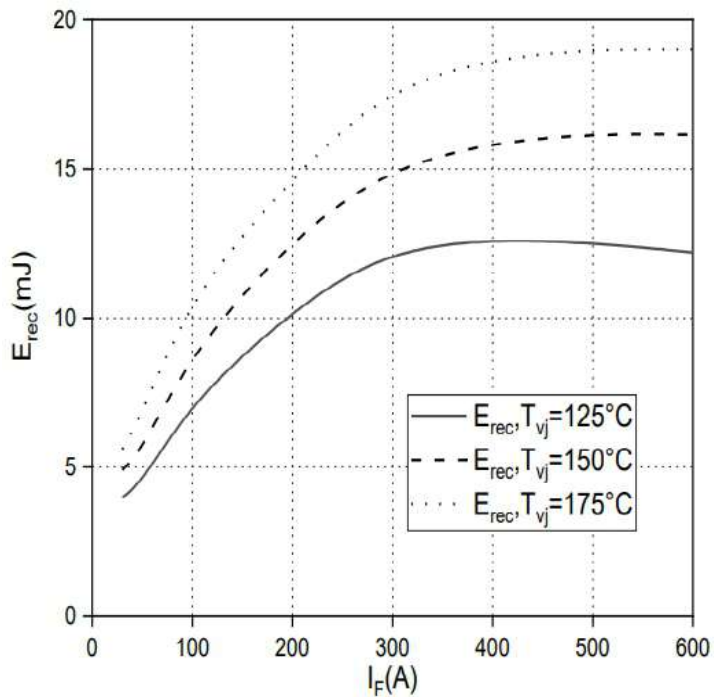
 $Z_{thJC} = f(t)$

 Reverse bias safe operating area IGBT, Inverter (RBSOA) $I_C = f(V_{CE})$,

 $V_{GE} = 15V/-8V$, $R_{Goff} = 1.5\Omega$, $T_{vj} = 175^\circ C$


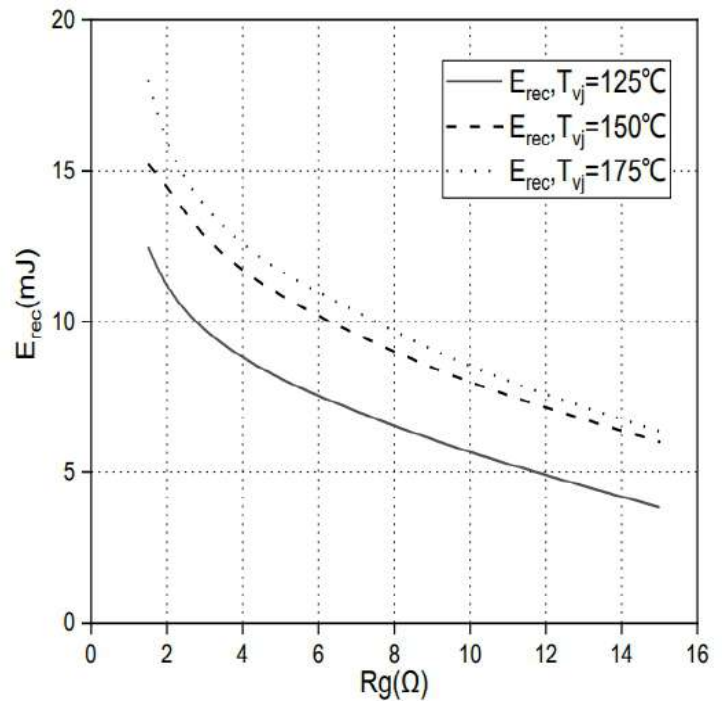
Forward characteristic of Diode, Inverter (typical)

 $I_F = f(V_F)$


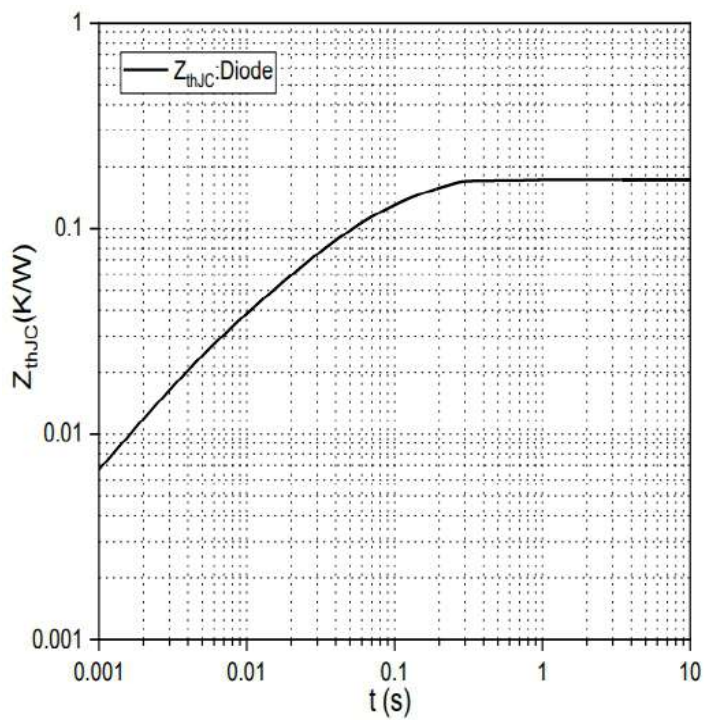
Switching losses Diode, Inverter (typical)

 $E_{rec} = f(I_F)$, $R_{gon} = 1.5\Omega$, $V_{CE} = 600V$


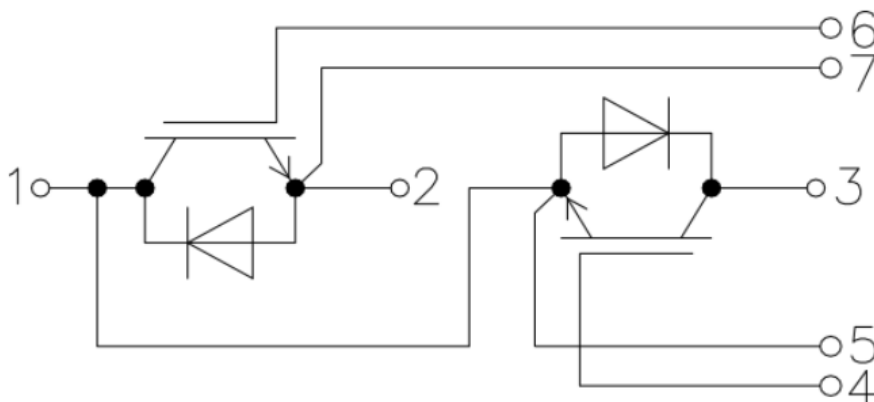
Switching losses Diode, Inverter (typical)

 $E_{rec} = f(R_g)$, $I_F = 300A$, $V_{CE} = 600V$


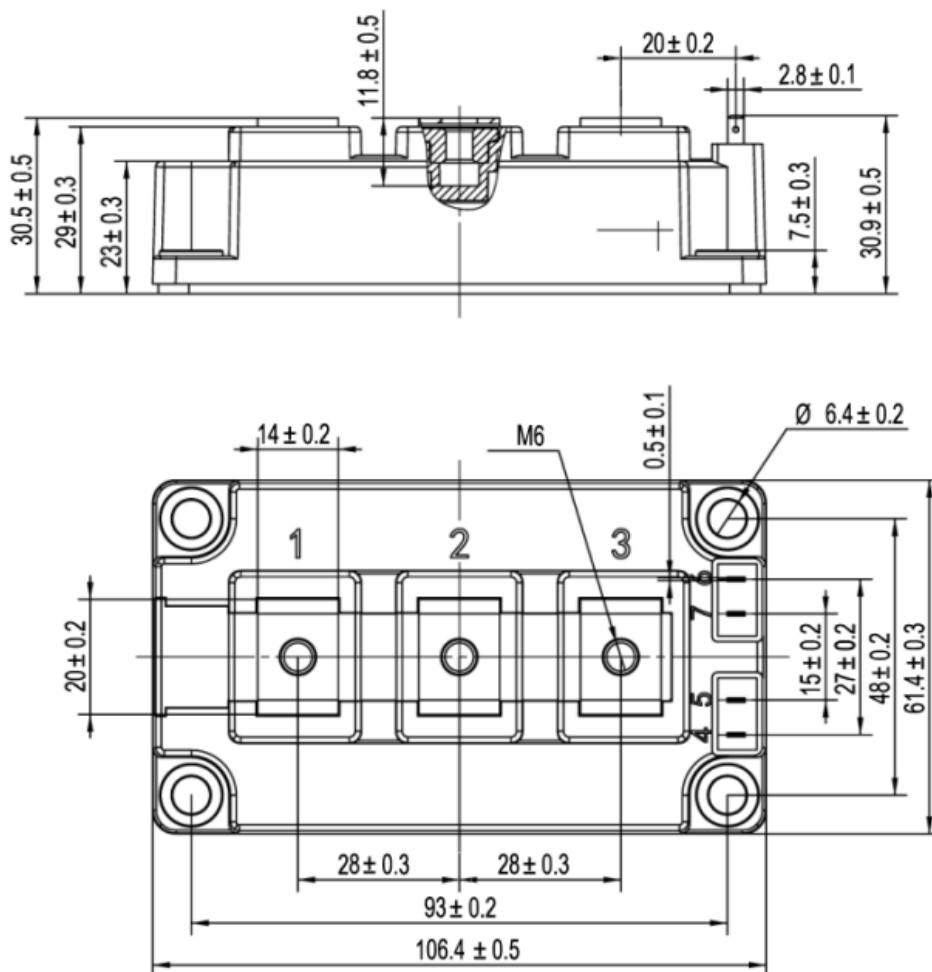
Transient thermal impedance Diode , Inverter

 $Z_{thJC} = f(t)$


Internal Circuit



Package Dimension Dimensions in Millimeters



Terms and Conditions of Usage of Technicon products

The data contained in this product datasheet is exclusively intended for technically trained staff. You and your technical departments will have to evaluate the suitability of the product for the intended application and the completeness of the product data with respect to such application. This product data sheet is describing the characteristics of this product for which a warranty is granted. Any such warranty is granted exclusively pursuant to the terms and conditions of the supply agreement. Therefore, products must be tested for the respective application in advance. Application adjustments may be necessary.

The user of Technicon products is responsible for the safety of their applications embedding Technicon products and must take adequate safety measures to prevent the applications from causing physical injury, fire, or other problems if any of Technicon products become faulty. The user is responsible for ensuring that the application design is compliant with all applicable laws, regulations, norms, and standards.

Except as otherwise explicitly approved by Technicon in a written document signed by authorized representatives of Technicon, Technicon products may not be used in any applications where a failure of the product or any consequences of the use thereof can reasonably be expected to result in personal injury.

No representation or warranty is given and no liability is assumed with respect to the accuracy, completeness and/or use of any information herein, including without limitation, warranties of non-infringement of intellectual property rights of any third party. Technicon does not assume any liability arising out of the applications or use of any product; neither does it convey any license under its patent rights, copyrights, trade secrets, or other intellectual property rights, nor the rights of others.

Technicon makes no representation or warranty of non-infringement or alleged non-infringement of intellectual property rights of any third party which may arise from applications. This document supersedes and replaces all information previously supplied and may be superseded by updates. Technicon reserves the right to make changes.

For any questions or suggestions, please contact us at info@technicon.asia .